

## Linear Building Block – Quad Low-Power Op Amp with Shutdown Modes

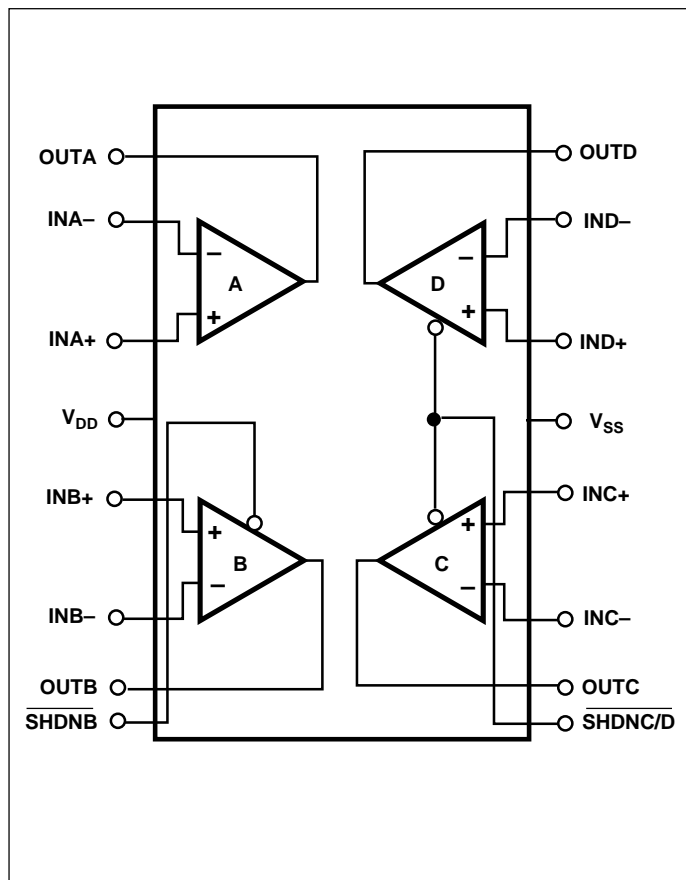
### FEATURES

- Optimized for Single-Supply Operation
- Small Package ..... 16-Pin QSOP
- Ultra Low Input Bias Current ..... Less than 100 pA
- Low Quiescent Current, Operating .... 20  $\mu$ A (Typ.)  
Shutdown Mode 6 $\mu$ A (Typ.)
- Rail-to-Rail Inputs and Outputs
- Operates Down to 1.8V
- Can Shut Down One, Two, or Three Op Amps Using Shutdown Pins in Shutdown Mode

### APPLICATIONS

- Power Management Circuits
- Battery Operated Equipment
- Consumer Products

### FUNCTIONAL BLOCK DIAGRAM



### GENERAL DESCRIPTION

The TC1030 is a quad CMOS operational amplifier designed for low power applications.

It has a typical operating supply current of 20 $\mu$ A which is constant over the supply voltage range of 1.8V to 5.5V.

Each op amp has rail-to-rail inputs and output which allow operation at low supply voltages with large input and output signal swings.

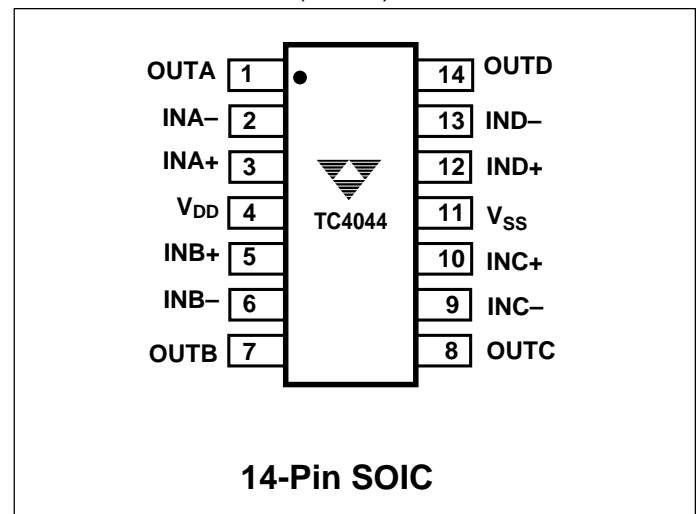
Two active low shutdown pins are provided. One pin disables op amp B while the other disables op amps C and D. Op amp A remains active always. When disabled the outputs of op amps B, C and D are in a high impedance state.

Packaged in a 16-pin QSOP, the TC1030 is ideal for battery operated applications.

### ORDERING INFORMATION

Part No.	Package	Temp. Range
TC1030EQR	16-Pin QSOP	- 40°C to +85°C
TC1043EV Evaluation Kit for Linear Building Block Family		

### PIN CONFIGURATION (QSOP)



# Linear Building Block – Quad Low-Power Op Amp with Shutdown Modes

## TC1030

### ABSOLUTE MAXIMUM RATINGS\*

Supply Voltage ..... 6.0V  
 Voltage on Any Pin: (With Respect to Supplies)  
 ..... ( $V_{SS} - 0.3V$ ) to ( $V_{DD} + 0.3V$ )  
 Operating Temperature Range: .....  $-40^{\circ}C$  to  $+85^{\circ}C$   
 Storage Temperature Range .....  $-55^{\circ}C$  to  $+150^{\circ}C$   
 Lead Temperature (Soldering, 10 sec) .....  $+260^{\circ}C$

\* Static-sensitive device. Unused devices must be stored in conductive material. Protect devices from static discharge and static fields. Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to Absolute Maximum Rating Conditions for extended periods may affect device reliability.

**ELECTRICAL CHARACTERISTICS:** Typical values apply at  $25^{\circ}C$ ,  $V_{DD} = 3.0V$ ;  $T_A = -40^{\circ}C$  to  $+85^{\circ}C$ ,  $V_{DD} = 1.8V$  to  $5.5V$ , unless otherwise specified.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
$V_{DD}$	Supply Voltage		1.8	—	5.5	V
<b>Shutdown Inputs</b>						
$V_{IH}$	Input High Threshold		$80\% V_{DD}$	—	—	V
$V_{IL}$	Input Low Threshold		—	—	$20\% V_{DD}$	V
$I_{SI}$	Shutdown Input Current, $\overline{SHDNB}$ or $\overline{SHDNC/D}$		—	—	$\pm 100$	nA
<b>Op Amps</b>						
$I_Q$	Supply Current, Operating	All Outputs Open, $\overline{SHDNB} = V_{DD}$ , $\overline{SHDNC/D} = V_{DD}$	—	20	32	$\mu A$
$I_{SHDN}$	Supply Current Shutdown Mode	$\overline{SHDNB} = V_{SS}$ $\overline{SHDNC/D} = V_{SS}$	—	6	10	$\mu A$
$R_{OUT(SD)}$	Output Resistance in Shutdown	$\overline{SHDNB} = V_{SS}$ , $\overline{SHDNC/D} = V_{SS}$	20	—	—	$M\Omega$
$C_{OUT(SD)}$	Output Capacitance in Shutdown	$\overline{SHDNB} = V_{SS}$ , $\overline{SHDNC/D} = V_{SS}$	—	—	5	pF
$T_{SEL}$	Select Time ( $V_{OUT}$ from $\overline{SHDNB}$ , $\overline{SHDNC/D} = V_{IH}$ )	$R_L = 10K\Omega$ to $V_{SS}$	—	15	—	$\mu sec$
$T_{DESEL}$	Deselect Time ( $V_{OUT}$ from $\overline{SHDNB}$ , $\overline{SHDNC/D} = V_{IL}$ )	$R_L = 10K\Omega$ to $V_{SS}$	—	20	—	nsec
$A_{VOL}$	Large Signal Voltage Gain	$R_O = 10 K\Omega$ , $V_{DD} = 5V$	—	100	—	V/mV
GBWP	Gain-Bandwidth Product	$V_{DD} = 1.8$ to $5.5V$ ; $V_O = V_{DD}$ to $V_{SS}$	—	90	—	KHz
$V_{ICMR}$	Common Mode Input Voltage Range		$V_{SS} - 0.2$	—	$V_{DD} + 0.2$	V
$V_{OS}$	Input Offset Voltage	$V_{DD} = 3V$ , $V_{CM} = 1.5V$ , $T_A = 25^{\circ}C$ , $T_A = -40^{\circ}C$ to $85^{\circ}C$		$\pm 100$ $\pm 0.3$	$\pm 500$ $\pm 1.5$	$\mu V$ mV
$I_B$	Input Bias Current	$T_A = 25^{\circ}C$ ; $V_{CM} = V_{DD}$ to $V_{SS}$	-100	50	100	pA
$V_{OS(DRIFT)}$	Average Input Offset Voltage Drift	$V_{DD} = 3V$ ; $V_{CM} = 1.5V$	—	4	—	$\mu V/^{\circ}C$
SR	Slew Rate	$C_L = 100$ pF, $R_L = 1 M\Omega$ to GND, Gain = 1 $V_{IN} = V_{SS}$ to $V_{DD}$	—	35	—	mV/ $\mu sec$
$V_{OUT}$	Output Signal Swing	$R_L = 10 K\Omega$	$V_{SS} + 0.05$	—	$V_{DD} - 0.05$	V
CMRR	Common Mode Rejection Ratio	$T_A = 25^{\circ}C$ ; $V_{DD} = 5V$ ; $V_{CM} = V_{DD}$ to $V_{SS}$	70	—	—	dB
PSRR	Power Supply Rejection Ratio	$T_A = 25^{\circ}C$ ; $V_{CM} = V_{SS}$ ; $V_{DD} = 1.8V$ to $5V$	80	—	—	dB

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TC1030

**ELECTRICAL CHARACTERISTICS (CON'T):** Typical values apply at 25°C,  $V_{DD} = 3.0V$ ;  $T_A = -40^\circ C$  to  $+85^\circ C$ ,  $V_{DD} = 1.8V$  to  $5.5V$ , unless otherwise specified.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
$I_{SRC}$	Output Source Current	$V_{IN+} = V_{DD}$ , $V_{IN-} = V_{SS}$ Output Shorted to $V_{SS}$ $V_{DD} = 1.8V$ ; Gain = 1	3	—	—	mA
$I_{SINK}$	DC Output Sink Current	$V_{IN+} = V_{SS}$ , $V_{IN-} = V_{DD}$ Output Shorted to $V_{DD}$ $V_{DD} = 1.8V$ ; Gain = 1	4	—	—	mA
$e_n$	Input Noise Voltage	0.1 Hz to 10 Hz	—	10	—	$\mu V_{pp}$
	Input Noise Density	1 KHz	—	125	—	$nV/\sqrt{Hz}$

## DETAILED DESCRIPTION

The TC1030 is one of a series of very low-power, Linear Building Block products targeted at low-voltage, single-supply applications. The TC1030 minimum operating voltage is 1.8V, and maximum supply current is only 32  $\mu A$  (fully enabled). It combines four op amps in a single package.

Microchip's op amps are internally compensated to be unity-gain stable and have a typical gain-bandwidth product of 90 KHz with typical slew rates of 35 V/msec.

The amplifier's input range extends beyond both supplies by 200mV and the outputs will swing to within several millivolts of the supplies depending on the load current being driven.

Two shutdown mode pins are incorporated for easy adaptation to system power management schemes. In this state, the shutdown pins allow the user to power on one, two, three, or all four op amps (see Table 1 on next page). Pin  $\overline{SHDNB}$  can be used to disable op amp B and pin  $\overline{SHDNC/D}$  to disable op amps C and D. Op amp A is always powered on regardless of the states of the shutdown pins. When both shutdown pins are low, the total quiescent current of the TC1030 is only 6  $\mu A$ , typical.

Input offset voltage is 500 $\mu V$  max at 25°C with an input bias current of less than 100pA. This makes the TC1030 extremely suitable for precision, low power applications.

## TYPICAL APPLICATIONS

The TC1030 lends itself to a wide variety of applications, particularly in battery-powered systems. It typically finds application in power management, process supervisory, and interface circuitry.

### Voice Band Receive Filter

The majority of spectral energy for human voices is found to be in a 2.7 KHz frequency band from 300 Hz to 3 KHz. To properly recover a voice signal in applications such as radios, cellular phones, and voice pagers a low-power

bandpass filter that is matched to the human voice spectrum can be implemented using Microchip's CMOS op amps. Figure 1 shows a unity gain multi-pole Butterworth filter with ripple less than 0.15 dB in the human voice band. The lower 3 dB cut-off frequency is 70 Hz (single order response) while the upper cut-off frequency is 3.5KHz (fourth order response).

### Supervisory Audio Tone (SAT) Filter for Cellular

Supervisory Audio Tones (SAT) provide a reliable transmission path between cellular subscriber units and base stations. The SAT tone functions much like the current/voltage used in land line telephone systems to indicate that a phone is off the hook. The SAT tone may be one of three frequencies: 5970, 6000, or 6030 Hz. A loss of SAT implies that channel conditions are impaired and if SAT is interrupted for more than 5 seconds a cellular call is terminated.

Figure 2 shows a high Q (30) second order SAT detection bandpass filter using Microchip's CMOS op amp architecture. This circuit nulls all frequencies except the three SAT tones of interest.

## EVALUATION KIT

The TC1043EV consists of a four-inch by six-inch pre-wired application circuit board. Pre-configured circuits include a pulse width modulator, wake-up timer, function generator, and others. On-board current meter terminals, voltage regulator, and a user-prototyping area speed circuit development. Please contact your local Microchip Semiconductor representative for more information.

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## TC1030

Table 1. TC1030 Shutdown Power Control Logic

$\overline{\text{SHDNC/D}}$	$\overline{\text{SHDNB}}$	Op Amps Enabled	Op Amps Disabled	Max. Device Supply Current
$V_{IL}$	$V_{IL}$	A	B,C,D	10 $\mu\text{A}$
$V_{IL}$	$V_{IH}$	A, B	C, D	16 $\mu\text{A}$
$V_{IH}$	$V_{IL}$	A, C, D	B	24 $\mu\text{A}$
$V_{IH}$	$V_{IH}$	A, B, C, D	None	32 $\mu\text{A}$

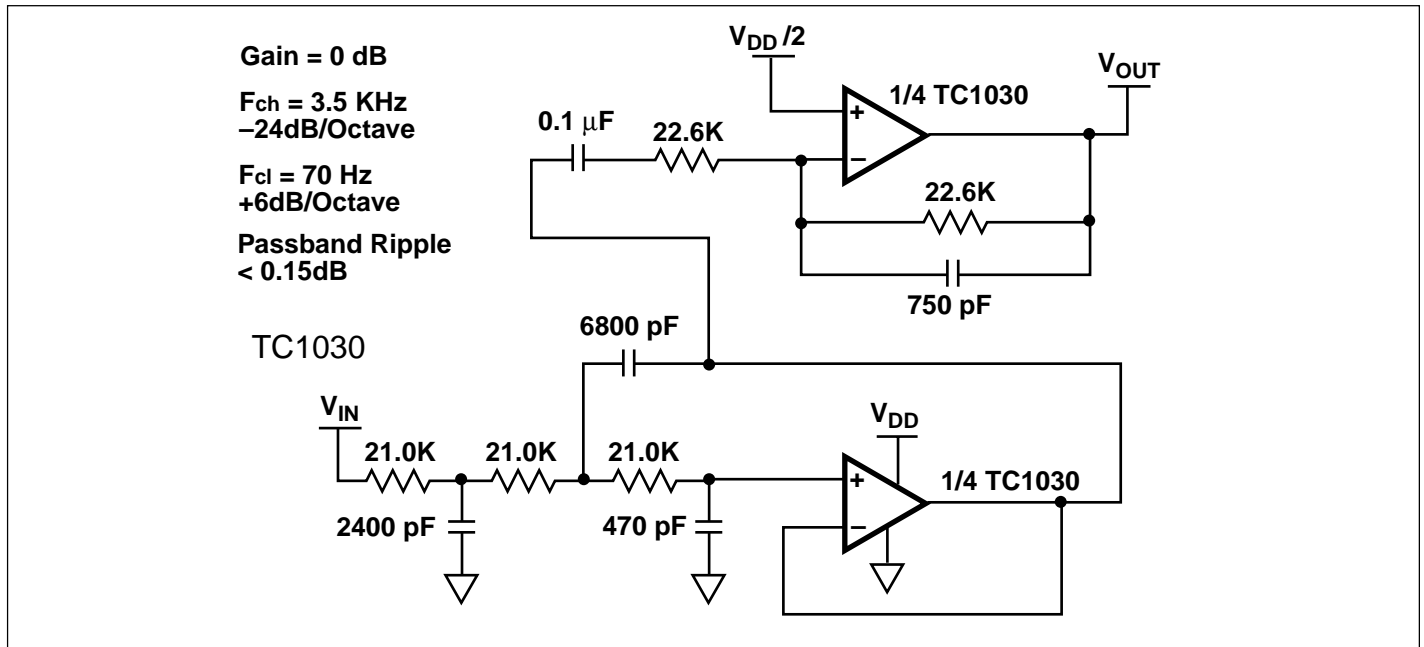


Figure 1. Multi-Pole Butterworth Voice Band Receiver Filter

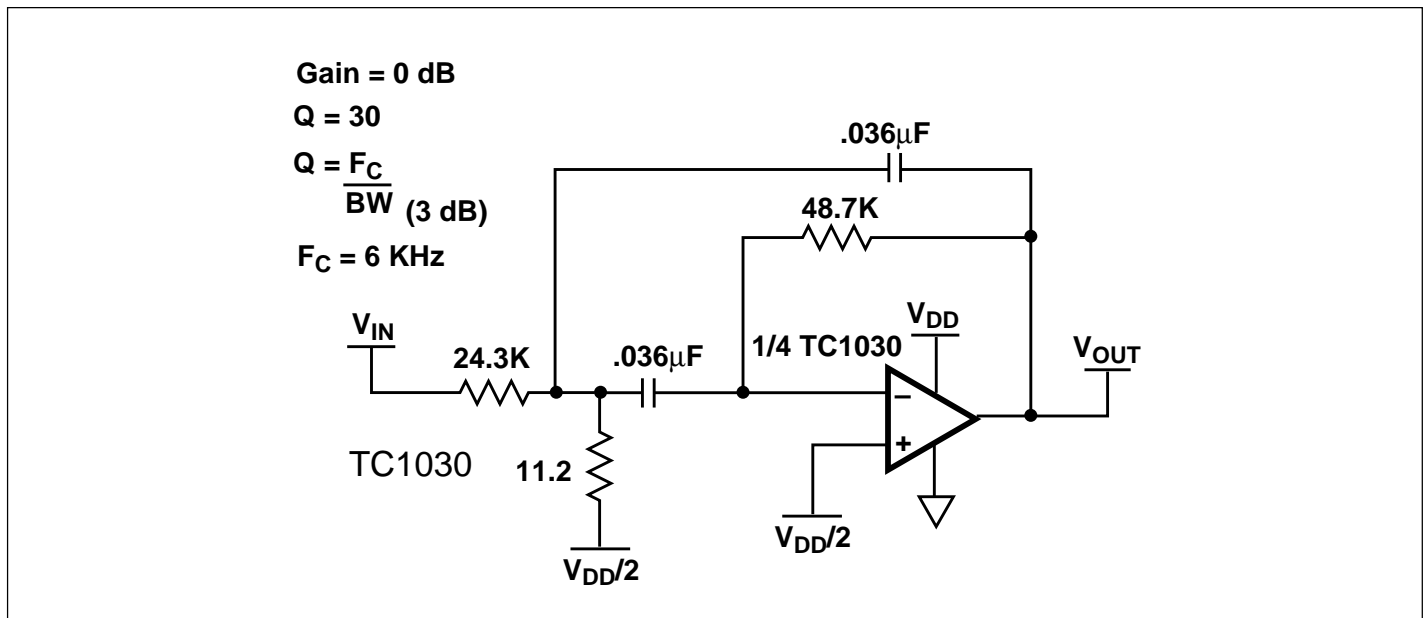
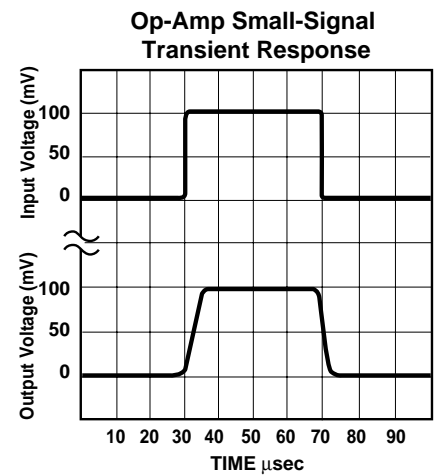
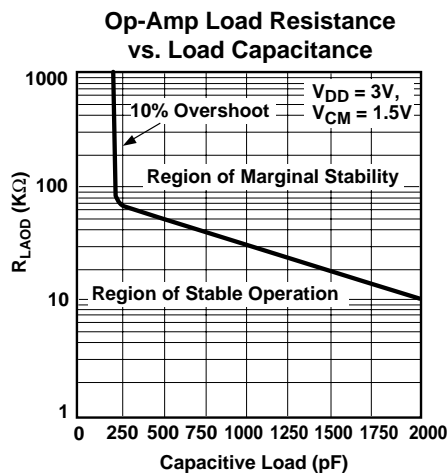
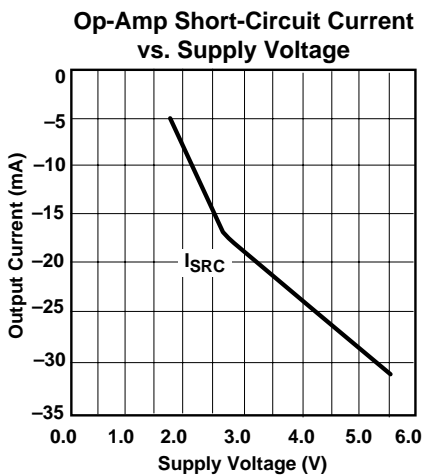
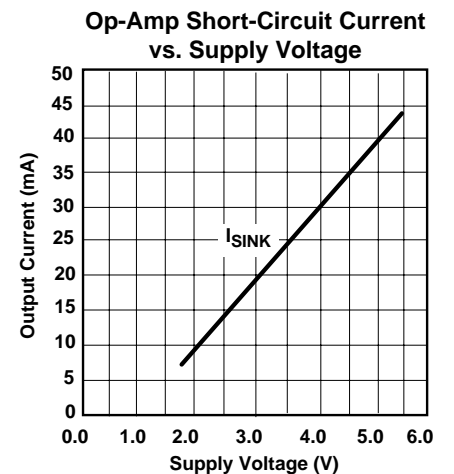
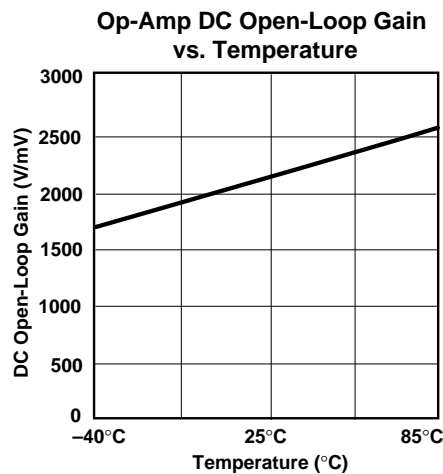
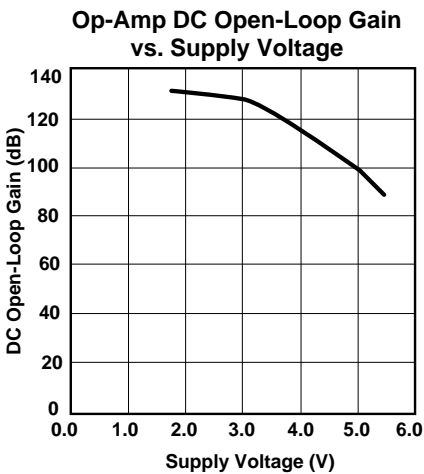
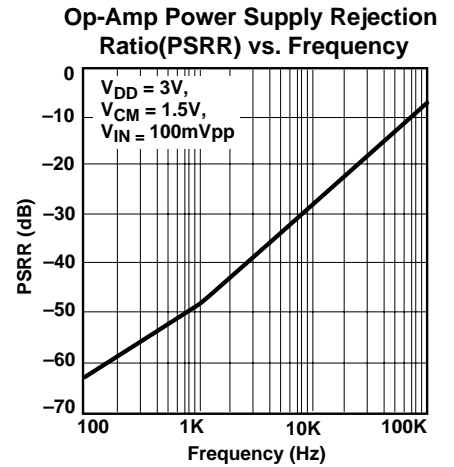
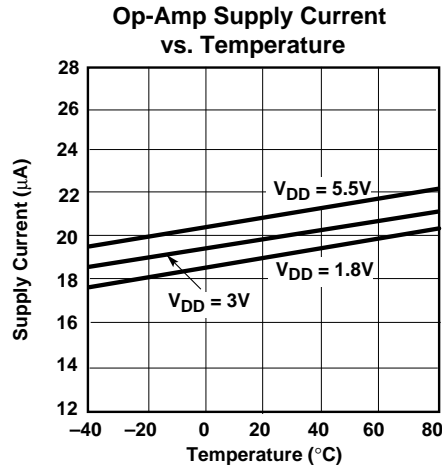
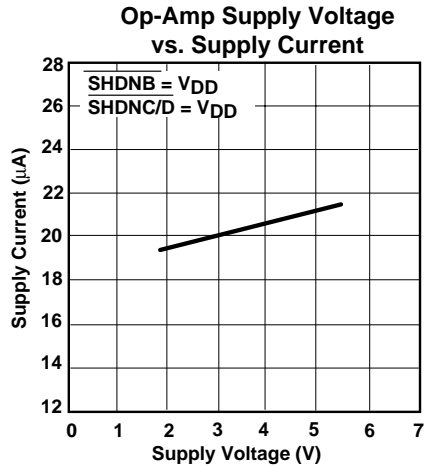


Figure 2. Second Order SAT Bandpass Filter

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TC1030

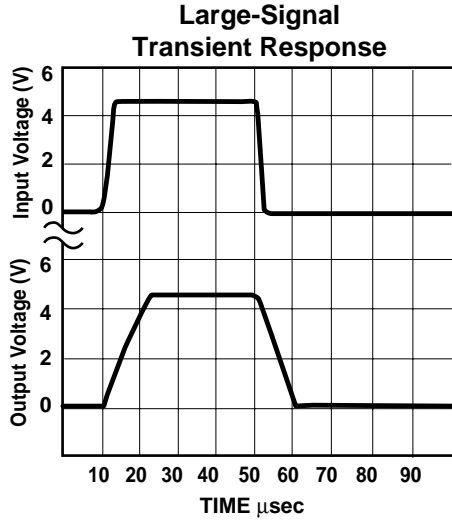
## TYPICAL CHARACTERISTICS CURVES



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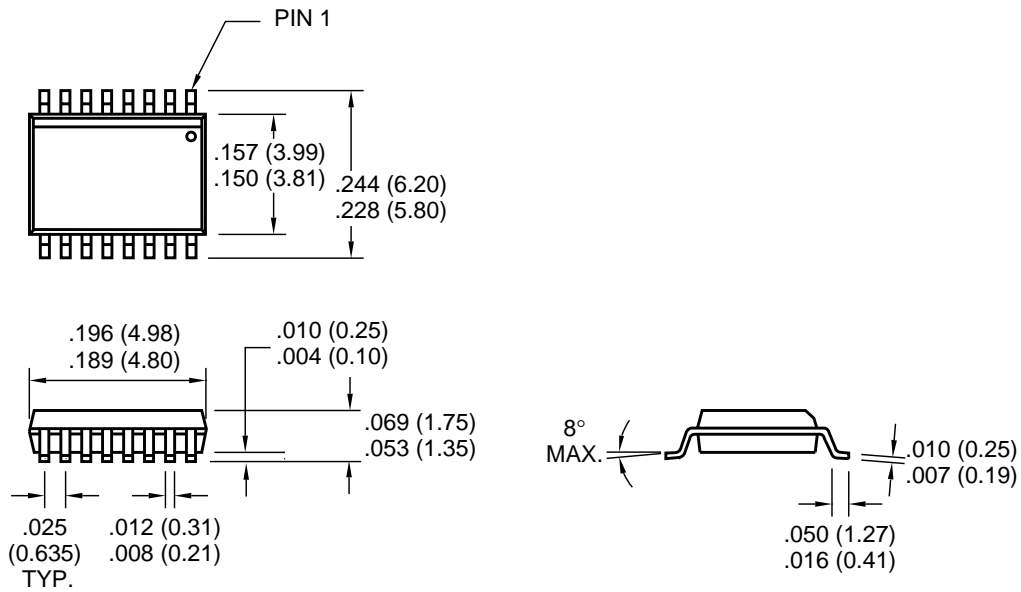
TC1030

## TYPICAL CHARACTERISTICS CURVE



## PACKAGE DIMENSIONS

### 16-Pin QSOP (Narrow)



Dimensions: inches (mm)



## WORLDWIDE SALES AND SERVICE

### AMERICAS

#### Corporate Office

2355 West Chandler Blvd.  
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Tel: 480-792-7200 Fax: 480-792-7277  
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Tel: 631-273-5305 Fax: 631-273-5335

#### San Jose

Microchip Technology Inc.  
2107 North First Street, Suite 590  
San Jose, CA 95131  
Tel: 408-436-7950 Fax: 408-436-7955

#### Toronto

6285 Northam Drive, Suite 108  
Mississauga, Ontario L4V 1X5, Canada  
Tel: 905-673-0699 Fax: 905-673-6509

### ASIA/PACIFIC

#### China - Beijing

Microchip Technology Beijing Office  
Unit 915  
New China Hong Kong Manhattan Bldg.  
No. 6 Chaoyangmen Beidajie  
Beijing, 100027, No. China  
Tel: 86-10-85282100 Fax: 86-10-85282104

#### China - Shanghai

Microchip Technology Shanghai Office  
Room 701, Bldg. B  
Far East International Plaza  
No. 317 Xian Xia Road  
Shanghai, 200051  
Tel: 86-21-6275-5700 Fax: 86-21-6275-5060

#### Hong Kong

Microchip Asia Pacific  
RM 2101, Tower 2, Metroplaza  
223 Hing Fong Road  
Kwai Fong, N.T., Hong Kong  
Tel: 852-2401-1200 Fax: 852-2401-3431

#### India

Microchip Technology Inc.  
India Liaison Office  
Divyasree Chambers  
1 Floor, Wing A (A3/A4)  
No. 11, O'Shaughnessy Road  
Bangalore, 560 025, India  
Tel: 91-80-2290061 Fax: 91-80-2290062

#### Japan

Microchip Technology Intl. Inc.  
Benex S-1 6F  
3-18-20, Shinyokohama  
Kohoku-Ku, Yokohama-shi  
Kanagawa, 222-0033, Japan  
Tel: 81-45-471-6166 Fax: 81-45-471-6122

#### Korea

Microchip Technology Korea  
168-1, Youngbo Bldg. 3 Floor  
Samsung-Dong, Kangnam-Ku  
Seoul, Korea  
Tel: 82-2-554-7200 Fax: 82-2-558-5934

### ASIA/PACIFIC (continued)

#### Singapore

Microchip Technology Singapore Pte Ltd.  
200 Middle Road  
#07-02 Prime Centre  
Singapore, 188980  
Tel: 65-334-8870 Fax: 65-334-8850

#### Taiwan

Microchip Technology Taiwan  
11F-3, No. 207  
Tung Hua North Road  
Taipei, 105, Taiwan  
Tel: 886-2-2717-7175 Fax: 886-2-2545-0139

### EUROPE

#### Australia

Microchip Technology Australia Pty Ltd  
Suite 22, 41 Rawson Street  
Epping 2121, NSW  
Australia  
Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

#### Denmark

Microchip Technology Denmark ApS  
Regus Business Centre  
Lautrup høj 1-3  
Ballerup DK-2750 Denmark  
Tel: 45 4420 9895 Fax: 45 4420 9910

#### France

Arizona Microchip Technology SARL  
Parc diActivite du Moulin de Massy  
43 Rue du Saule Trapu  
Batiment A - 1er Etage  
91300 Massy, France  
Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

#### Germany

Arizona Microchip Technology GmbH  
Gustav-Heinemann Ring 125  
D-81739 Munich, Germany  
Tel: 49-89-627-144 0 Fax: 49-89-627-144-44

#### Germany

Analog Product Sales  
Lochhamer Strasse 13  
D-82152 Martinsried, Germany  
Tel: 49-89-895650-0 Fax: 49-89-895650-22

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Arizona Microchip Technology SRL  
Centro Direzionale Colleoni  
Palazzo Taurus 1 V. Le Colleoni 1  
20041 Agrate Brianza  
Milan, Italy  
Tel: 39-039-65791-1 Fax: 39-039-6899883

#### United Kingdom

Arizona Microchip Technology Ltd.  
505 Eskdale Road  
Winnersh Triangle  
Wokingham  
Berkshire, England RG41 5TU  
Tel: 44 118 921 5869 Fax: 44-118 921-5820

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